Sign Reversals of ac Magnetoconductance in Isolated Quantum Dots

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We have measured the electrom agnetic response of micron-size isolated mesoscopic G aA s/G aA lA s square dots down to temperature T = 16m K, by coupling them to an electrom agnetic microresonator. Both dissipative and non dissipative responses exhibit a large magnetic eld dependent quantum correction, with a characteristic ux scale which corresponds to a ux quantum in a dot. The real (dissipative) magnetoconductance changes sign as a function of frequency for low enough density of electrons. The signal observed at frequency below the mean level spacing , corresponds to a negative magnetoconductance, which is opposite to the weak localization seen in connected system s, and becomes positive at higher frequency. We propose an interpretation of this phenomenon in relation to fundamental properties of energy level spacing statistics in the dots.

There are several ways of measuring the electrical conductance of a metallic sample. The most common one is to drive a current through it and measure the voltage drop between the connected wires. But, it is also possible to measure the conductance without making any connection to the sample. Capacitance and inductance measurements at nite frequency provide such a way. W hen a metallic sample of typical size a is inserted into a coil, it acquires a magnetic moment m ' Ia², where I is the eddy current induced in the sample. This changes the impedance of the coil by a quantity: Z (!) ' L ! _m (!)=V where V is the volume of the coil of inductance L and _m is the magnetic susceptibility of the sample related to the conductance G_m, the ratio between I and the induced electrom otive force by [1]:

$$_{m}$$
 (!) = i! $_{0}G_{m}$ (!) a^{4} (1)

Similarly the adm ittance change of a capacitance C due to the insertion of a metallic sample reads: Z¹ (!) ' C! $_{e}$ (!)=V where V is the volume of the capacitor and $_{e}$ (!), the electrical polarisability of the sample, is related to its electric conductance G $_{e}$ (de ned as ratio between polarization current and unscreened voltage drop through the sample), by [2]:

$$_{e}(!) = \frac{G_{e}(!)a^{2}}{i! 0}$$
 (2)

In the classical lim it at low frequency (such that the size of the sample is much smaller than the skin depth) G_m is real and identical to the D rude conductance $G_D = a$ within a num erical constant which depends on the geom – etry of the sample. On the other hand due to screening of the electric eld inside the metal [3], and for ! < = 0, G_e is dominated by its in aginary part: Im $G_e = !a_0$. Its real part is equal to:

$$ReG_{e} = (_{0}!a)^{2} = G_{D}$$
 (3)

In a mesoscopic sample, which length is smaller than the electronic phase coherence length, it was shown theoretically [4{8] that the conductance strongly depends on

the way it is measured. More precisely, it is very sensitive to the coupling between the mesoscopic sample and the macroscopic classical apparatus. W hen a sample is connected with wires, (that is to say when the coupling is strong), relative quantum corrections on the conductance are of the order of 1=g where $g = G_D = (e^2 = h)$ [9]. This result concerning the dissipative components of the conductance are unchanged for unconnected sam ples provided that the energy level spectrum is continuous [7] i.e. the typical level width is much larger than the mean level spacing . Note how ever that the quantum corrections of ReG_e and ReG_m are opposite in sign. Furthermore Im G_m is expected to be nite and directly related to persistent currents and more generally orbital magnetism in the sample [4(6,10]. At the same time $\operatorname{Im} G_{e}$ acquires a magnetic eld dependence related to quantum corrections to the electrical polarisability [11].

On the other hand, if the discrete spectrum limit is achieved, quantum coherence of the sample gives rise to giant magnetoconductance [6{8] whose sign and am plitude are determined by the order relation between the relevant energy scales: h!; ; ;k_BT.Preliminary experiments [12] on an array of A haronov-Bohm rings coupled to a resonator, have shown that the investigation of ac conductance on isolated samples in the

discrete spectrum lim it is indeed possible.

In this letter, we report the measurement of the electromagnetic response of an array of mesoscopic square dots made from G aA s/G aA IA s 2D electron gas at frequencies both below and above energy level spacing. Sign reversals of magnetoconductance were observed which can be interpreted in relation to the sensitivity to magnetic eld of level spacings distribution in the dot, according to random matrix theory.

As in the previous experiment [12], the mesoscopic samples are coupled to an electromagnetic microresonator, made of two N iobium wires (d = 4 m spaced, 1 m width and 20cm long) deposited in a meandering geometry on a sapphire substrate. The superconducting material is used to reduce losses and therefore get a high

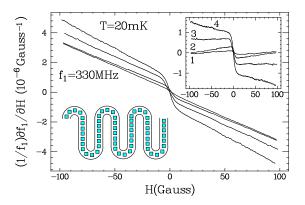


FIG.1. Field derivative of resonance frequency for the rst harm onics of the resonator, the di erent curves correspond to successive illum inations of the sam ple.Inset, bottom : schem atic picture of the resonator and the square dots. Inset, top : data obtained after substraction of the empty resonator contribution.

quality factor (80000 without any sample). The resonance conditions are: $L = \frac{n}{2}$, where n = 1;2;3::: and L is the length of the superconducting wires and the electrom agnetic wavelength. The fundam ental resonance frequency is of the order of 330M Hz. This experiment allow s us to detect extrem ely small variations of frequency and quality factor: $\frac{f}{f}$ (Q¹) 10⁹. In the presence of mesoscopic samples deposited on the top, (with a spacer consisting of a 1 m thick mylar sheet), the characteristics of the resonance resonance modified. The dissipation in the samples a ects the quality factor, whereas the non dissipative response a ects the resonance frequency:

$$\frac{f}{f} = kN_s^{0}(!); (Q^{1}) = kN_s^{0}(!)$$
(4)

where $(!) = {}_{e}(!) + {}_{m}(!)$ is the average complex susceptibility of a dot [2], N_s is the number of sam ples and k is a geometrical coupling coe cient which is of the order of $1=Ld^2$, where d is the distance between the two Niobium wires. The sample studied in this experim ent, was an array of 10⁵ disconnected square dots etched, using electron beam lithography techniques, in a sem iconductor hetero junction G aA s/G aA lA s. The electron concentration of the two dimensional electron gas (2DEG) before etching was $n_e = 3:10^{11}$ cm⁻² and elastic mean free path $l_e = 10 \text{ m}$. This electronic density was strongly depressed in etched samples but could be recovered with illum ination. For this purpose an electrolum inescent diode was placed next to the resonator, allow ing to change gradually the num ber of electrons in the squares by transient illum ination of the sam ples (between 30s and 2mn). The measurements were always done at least one hour after the illum ination was stopped, in order to ensure good stability of the sam ples. The size of the squares a = 1.5 m was estimated from weak local-

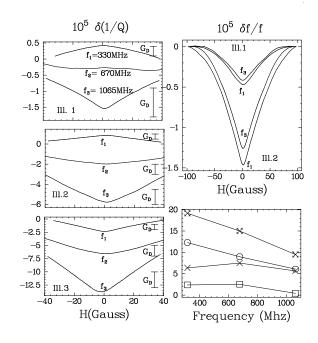


FIG.2. Field dependence of real and imaginary susceptibilities for several resonance frequencies and illum inations. The amplitude of the signal corresponding to the D rude value G_D is estimated for each illum ination assuming that $^{0}(f_1)$ is proportional to G_D and that illum ination 4 corresponds to saturation i.e. a density of 6 10^{11} eL/cm². Bottom right: frequency dependence of 0 f=0 f in units of $10^{-7} \text{ Gauss}^{-1}$.

ization experiments on connected samples made together with the squares. The transport in the samples can thus be considered as ballistic. The mean level spacing in a square = $2 \frac{h^2}{ma^2}$, (m is the electron mass) is independent of the electronic density. It is of the order of 38m K which corresponds to a frequency of 760M Hz. Resonator and diode are enclosed in a metallic box, protecting from electrom agnetic noise, and cooled with a dilution fridge down to 16m K.

We have measured the magnetic eld dependence of the resonance frequency and quality factor for several harmonics ($f_1 = 330M \text{ Hz}$, $f_2 = 670M \text{ Hz}$, $f_3 = 1065M \text{ Hz}$) and after successive illuminations. The dc magnetic eld wasmodulated at low frequency (30H z) with a small coll close to the sample. This allows measurem ent of derivatives of resonance frequency (see g.1) and quality factor with respect to magnetic eld. The signal of the samples consists in step-like features on the eld dependence of $@f=@h / @ ^0(H)=@H$ and $@Q ^1=@h / @ ^0(H)=@H$ whose width ' 10 G auss corresponds approximatively to half a ux quantum in a square. In the case of @f=@h the contribution of the empty resonator, linear in magnetic eld, has to be sub-

tracted from the signal. A fter integration, the magnetoconductance G(H) / (H) = (H) (0) of the sam ples can be deduced from these measurements (see g2). We observe that both real and imaginary com – ponents present the striking triangular shape observed in experiments on connected ballistic dots of similar geom etries which is believed to be related to the classical integrability of these system s [13].

 0 (H) and 00 (H) are found to have very di erent behaviors as a function of frequency. 0 (H) is always positive, its amplitude drastically increases with the rst successive illum inations which correspond to an increasing num ber of electrons, and then tends to saturate. For a xed number of electrons it is nearly independent of frequency [14]. On the other hand 00 (H) is observed to be negative for the rst harm onics and sm all electronic density and becomes positive with increasing frequency and electronic density. This sign change of the magnetoconductance is the most striking result of our work.

The tem perature dependence of the signals were also measured. The tem perature decay depicted in g.3 is found to be independent of frequency and nearly identical for ⁰ and ⁰⁰. It cannot be tted with an exponential as was the case for the ring experiment. The characteristic tem perature scale of this decay slightly increases with the num ber of electrons in the dots.

In the following we want to compare our results with theoretical predictions on orbital magnetism and polarisability. The orbital susceptibility of ballistic squares has been calculated by several authors, it is found to be param agnetic in zero eld, in agreem ent with experim ental results on the dcm agnetization of G aA s/G aA IA s squares [15]. Our results on the other hand indicate unam biquously low eld diam agnetism, just like the previous ac experim ent on an ensemble of rings [12]. W e note how ever that the amplitude of ${}^{0}(H)$ measured at saturation correspond to an average orbital susceptibility of the order of the theoretical prediction: $ga^2 = m$ [16]. In the case of an electric coupling, the signal can be related to the average magneto-polarisability of the squares. This quantity has been recently calculated [11], its sign (which corresponds to an increase of polarisability with magnetic eld) could explain our experimental results on ⁰(H). Nevertheless, according to these predictions, the magneto-polarisability is proportional to 1=g and also to the Thom as-Ferm iscreening length. Thus it should decrease with the num ber of electrons, which is in com plete contradiction with what we measured. So, the ⁰(H) deserves understanding of our measurem ents on further theoretical investigations.

We now consider the dissipative part of the response. The low frequency classical absorption of a metallic grain in an ac electric eld has been shown [3,8] to be described by the electric conductance G_e (see expression (3)). This result initially derived for 3D systems can easily be extended to 2D samples provided that the electric

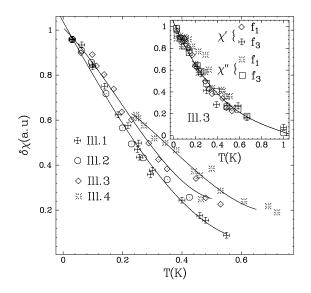


FIG.3. Rescaled, tem perature dependences of ⁰ for the rst harm onics and various num ber of electrons corresponding to successive illum inations (continuous lines are only guides for the eyes). Inset: tem perature dependence of ⁰ and ⁰ for the rst and third harm onics.

eld lies in their plane. The ratio between \magnetic" losses described by G_m and \electric" losses in the resonator is then simply given by: $r = (Z_0 G_D)^2$, where $Z_0 = \frac{0}{0} = 377$ is the vacuum in pedance. In our case r varies between 8 and 400 depending on the electronic density in the dots. Therefore, we conclude that the dom inant contribution to $0^{(0)}$ com es from G_m . Using expression (1) relating G_m to the measured quantity

 $^{\odot}$ (H), it is possible to express the m agnetoconductance m easured for several frequencies and num ber of electrons in units of G $_{\rm D}$ as shown in g2. Note that in m ost cases the m agneto-conductance is of the order of G $_{\rm D}$ as expected for a discrete level system .

The eld dependence of the dissipation of A haronov-Bohm rings in a time dependent ux has been extensively studied [4{7]. It is straightforward to extend these results to singly connected geometries and estimate expected G_m (H) in our case. Let us recall the existence of two dimension contributions to G_m (H) in the limit where and T > : G off and Gdi. Goff related to inter-level transitions is expressed in term softhe the level

inter-level transitions is expressed in term softhe the level spacing distribution function R (s) which obeys universal rules of random m atrix theory [17,18]. It corresponds for H = 0 to G aussian O rthogonal Ensemble (GOE) and for su ciently large eld, in order that time reversal sym-m etry is broken, to G aussian U nitary Ensemble (GUE).

$$G_{off}(H) = G_{D} - \frac{(R_{GUE}(s) - R_{GOE}(s))}{(h! - s)^{2} + 2} ds$$
 (5)

On the other hand G_{di} is related to the relaxation of

persistent currents which always yields to positive magnetoconductance:

$$G_{di}(H) = G_{di}(GUE) \qquad G_{di}(GOE) = G_D \frac{1}{2} + \frac{2}{2}$$
 (6)

In the lim it where ! the magneto-conductance is dom insted by: $G_{off}(H)$ G_D (R_{GUE} (!) $R_{GOE}(!)$. The magnetoconductance is negative at ! < and changes sign at frequency of the order of as depicted in g.4.W e believe that the squares after illum ination 1 correspond to this situation. This change of sign is how ever expected to disappear when increases such as the condition: $G_2 > j G_1 j$ is realized. W e suggest that illum inations 3 and 4 correspond to this last situation. The increase of for successive illum inations is necessary to explain our results. It cannot be due to the contribution of electron-electron interactions (whose contribution decreases with increasing electron density [19]) but possibly to the increase of losses in the etched G aA s substrate. W e indeed observed a substantial decrease of Q after each illum ination. The electrom agnetic noise related to these losses is expected to contribute substantially to the level broadening [20,21]. Theory [6,7] also predicts, for canonicalensemble, changes of sign of the magnetoconductance with tem perature at T < which we have not observed, possibly because of lack of experimental points in the regim e where T

In conclusion these results show that ac conductance m easurements on isolated samples reveal indeed new physical features. G iant m agnetoconductance has been observed. Sign changes on the realpart are in agreement with the pioneer predictions of G orkov and E liashberg [18] on the sensitivity of the energy spectrum to time reversal breaking by m agnetic eld. The imaginary part whose amplitude is of the same order of m agnitude than the real one is in principle related to the orbital m agnetism in the dots. However its sign is not yet understood.

W e aknow ledge fruitfull discussions with B.Altshuler, Y.G efen, B.Schlovski and P.W alker.

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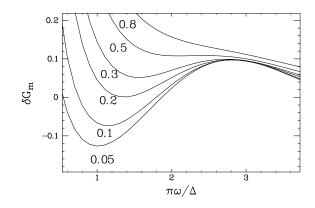


FIG.4. Calculated frequency dependence of G_m for different values of the ratio = .

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